Bipolar Transistors Silicon PNP/NPN Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

RN4907FE

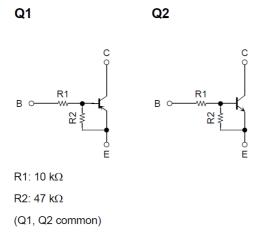
1. Applications

- Switching
- Inverter Circuits
- Interfacing
- Driver Circuits

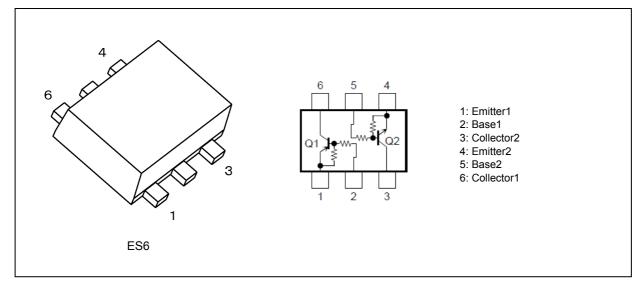
2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) Small package (Dual type)
- (3) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.

3. Equivalent Circuit



4. Packaging and Pin Assignment



Start of commercial production 2000-05 2021-08-18

5. Orderable part number

Orderable part number	AEC-Q101		Note		
RN4907FE,LF	— General Use				
RN4907FE,LXGF	YES	(Note 1)	Unintended Use (Note		
RN4907FE,LXHF	YES		Automotive Use		

Note 1: For more information, please contact our sales or use the inquiry form on our website.

6. Q1 Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-50	V
Collector-emitter voltage	V _{CEO}	-50	
Emitter-base voltage	V _{EBO}	-6	
Collector current	Ι _C	-100	mA

7. Q2 Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	
Emitter-base voltage	V _{EBO}	6	
Collector current	Ι _C	100	mA

8. Q1, Q2 Common Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteris	Symbol	Rating	Unit	
Collector power dissipation	(Note 1)	P _C	100	mW
Junction temperature		Тj	150	°C
Storage temperature		T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

9. Q1 Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = -50 V, I _E = 0 mA	_	—	-100	nA
Collector cut-off current	I _{CEO}	V _{CE} = -50 V, I _B = 0 mA	_	_	-500	
Emitter cut-off current	I _{EBO}	V _{EB} = -6 V, I _C = 0 mA	-0.081	_	-0.15	mA
DC current gain	h _{FE}	V _{CE} = -5 V, I _C = -10 mA	80	_	_	_
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = -5 mA, I _B = -0.25 mA	_	-0.1	-0.3	V
Input voltage (ON)	V _{I(ON)}	V _{CE} = -0.2 V, I _C = -5 mA	-0.7	_	-1.8	
Input voltage (off)	V _{I(off)}	V _{CE} = -5 V, I _C = -0.1 mA	-0.5	_	-1.0	
Transition frequency	f _T	V _{CE} = -10 V, I _C = -5 mA	_	200	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0 mA, f = 1 MHz		3	6	pF

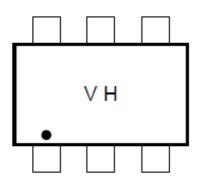
10. Q2 Electrical Characteristics (Unless otherwise specified, $T_a = 25 \text{ °C}$)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 50 V, I _E = 0 mA	_		100	nA
Collector cut-off current	I _{CEO}	V _{CE} = 50 V, I _B = 0 mA	_	_	500	
Emitter cut-off current	I _{EBO}	V _{EB} = 6 V, I _C = 0 mA	0.081		0.15	mA
DC current gain	h _{FE}	V _{CE} = 5 V, I _C = 10 mA	80	_	—	—
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 5 mA, I _B = 0.25 mA	_	0.1	0.3	V
Input voltage (ON)	V _{I(ON)}	V _{CE} = 0.2 V, I _C = 5 mA	0.7	_	1.8	
Input voltage (off)	V _{I(off)}	V _{CE} = 5 V, I _C = 0.1 mA	0.5		1.0	
Transition frequency	f _T	V _{CE} = 10 V, I _C = 5 mA	_	250	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0 mA, f = 1 MHz	_	3	6	pF

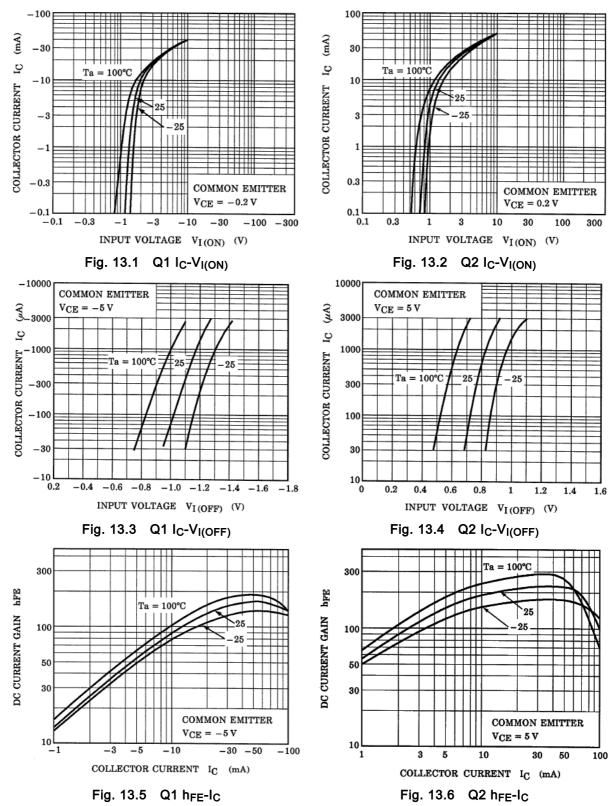
11. Q1, Q2 Common Electrical Characteristics (Unless otherwise specified, $T_a = 25$ °C)

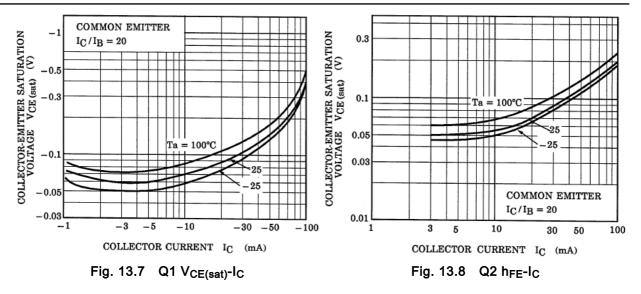
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input resistance	R ₁	-	7	10	13	kΩ
Resistor ratio	R1/R2	-	0.191	0.213	0.232	—

12. Marking



13. Characteristics Curves (Note)





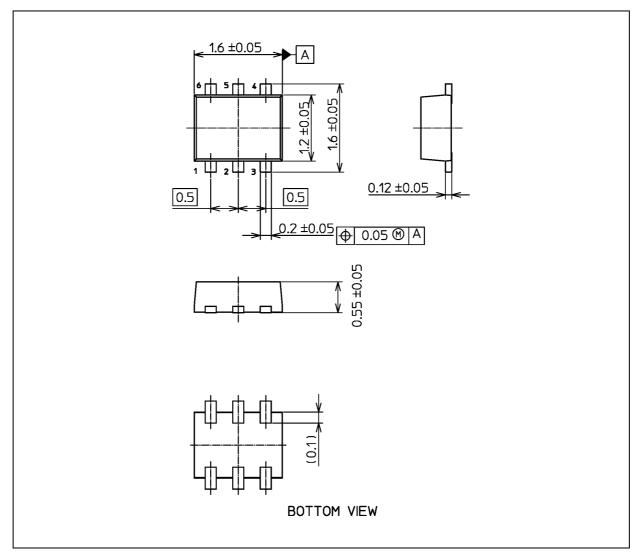
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



RN4907FE

Package Dimensions

Unit: mm



Weight: 3.0 mg (typ.)

	Package Name(s)
TOSHIBA: 1-2X1S	
Nickname: ES6	

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